

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









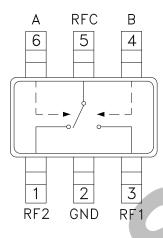
## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

### Typical Applications

The HMC595 / HMC595E is ideal for:

- Cellular/3G Infrastructure
- Private Mobile Radio Handsets
- WLAN, WiMAX & WiBro
- Automotive Telematics
- Test Equipment

### **Functional Diagram**



#### **Features**

Low Insertion Loss: 0.3 dB High Input IP3: +65 dBm

Isolation: 30 dB

Positive Control: 0/+3V to 0/+10V Ultra Small Package: SOT26

Included in the HMC-DK005 Designer's Kit

### **General Description**

The HMC595 & HMC595E are low-cost SPDT switches in 6-lead SOT26 packages for use in transmit/receive applications which require very low distortion at high incident power levels. The device can control signals from DC to 3 GHz and is especially suited for Cellular/3G infrastructure, WiMAX and WiBro applications with only 0.3 dB typical insertion loss. The design provides a 3 watt power handling and +65 dBm third order intercept at +8 Volt bias. RF1 and RF2 are reflective shorts when "Off". Control inputs A & B are compatible with CMOS and some TTL logic families. These products are form, fit and function replacements for HMC195 & HMC195E while offering superior electrical performance.

## Electrical Specifications,

 $T_A = +25^{\circ}$  C, VctI = 0/+5 Vdc (Unless Otherwise Stated), 50 Ohm System

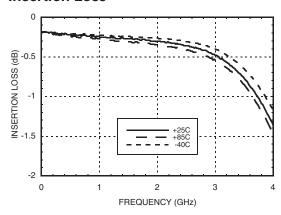
Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		0.25 0.3 0.4 0.5	0.5 0.6 0.7 0.8	dB dB dB dB	
Isolation		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz	26 22 18 14	30 26 24 18		dB dB dB dB
Return Loss		DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 3.0 GHz		30 25 22 20		dB dB dB dB
Input Power for 1dB Compression		0.5 - 3.0 GHz	32 35 37	35 38 39		dBm dBm dBm
		0.5 - 3.0 GHz		47 64 65		dBm dBm dBm
Switching Characteristics		DC - 3.0 GHz				
tRISE, tFAI tON, tOFF (50% CTL			80 120		ns ns	



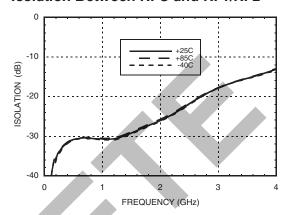


## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

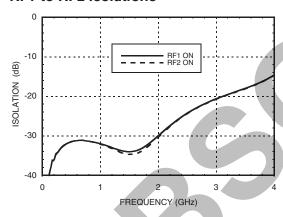
#### **Insertion Loss**



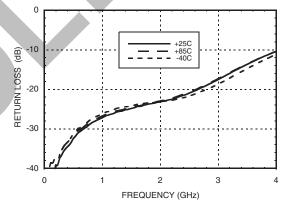
#### Isolation Between RFC and RF1/RF2



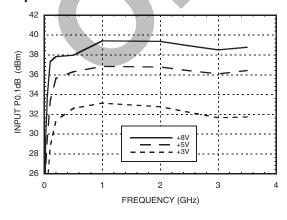
### RF1 to RF2 Isolations



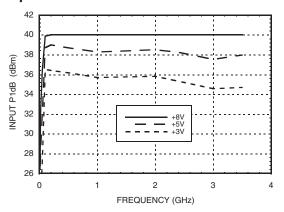
#### **Return Loss**



### Input P0.1dB vs. Vctl



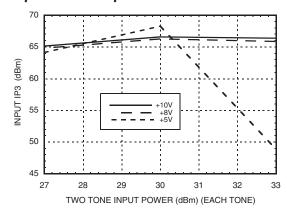
#### Input P1dB vs. Vctl



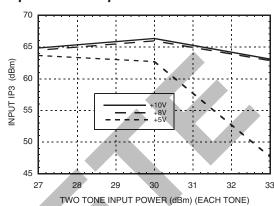


## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

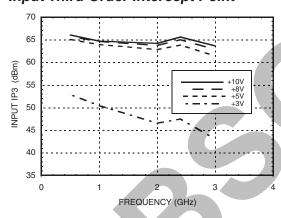
#### Input IP3 vs. Input Power @ 900 MHz



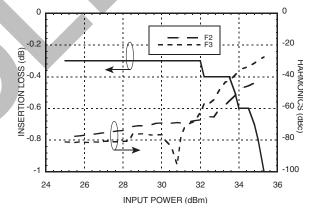
### Input IP3 vs. Input Power @ 1900 MHz



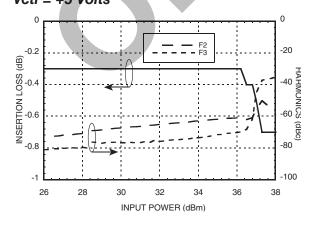
### **Input Third Order Intercept Point**



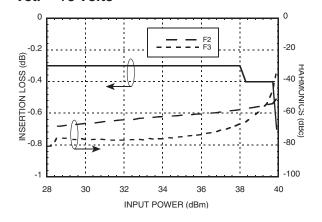
2nd & 3rd Harmonics @ 900 MHz Vctl = +3 Volts



### 2nd & 3rd Harmonics @ 900 MHz Vctl = +5 Volts



2nd & 3rd Harmonics @ 900 MHz Vctl = +8 Volts

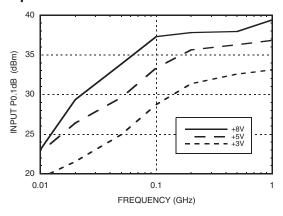




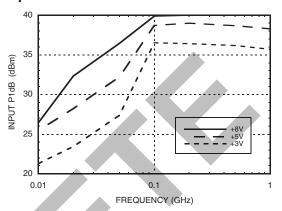


## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

### Input P0.1dB vs. Vctl



### Input P1dB vs. Vctl



### **Absolute Maximum Ratings**

Max. Input Power $V_{ctl} = 0/+8V$	0.5 - 2.5 GHz	39 dBm	
Control Voltage Ra	nge (A & B)	-0.2 to +12 Vdc	
Hot Switching Power V <sub>ctl</sub> = 0/+8V	39 dBm		
Channel Temperate	150 °C		
Continuous Pdiss ( (derate 6 mW/°C at	0.38W		
Thermal Resistanc	173 °C/W		
Storage Temperatu	-65 to +150 °C		
Operating Tempera	ature	-40 to +85 °C	
ESD Sensitivity		Class 1A	

DC Blocks are required at ports RFC, RF1 and RF2

### **Control Voltages**

State	Bias Condition
Low	0 to +0.2 Vdc @ 10 μA Typical
High	+3 Vdc @ 2μA Typical to +8 Vdc @ 40 μA Typical (± 0.2 Vdc)

#### Truth Table

Control Ir	put (Vctl)	Signal Path State		
АВ		RFC to RF1	RFC to RF2	
High Low		Off	On	
Low High		On	Off	

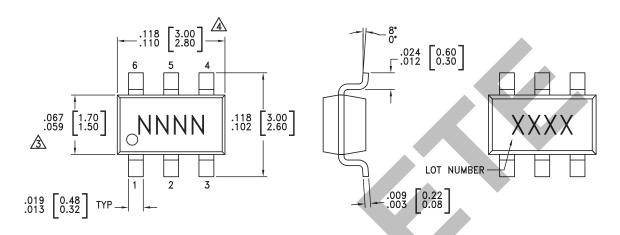


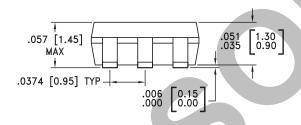




## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

### **Outline Drawing**





#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND

### Package Information

Part Number		Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC595		Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H595 XXXX
HMC595E RoHS-compliant Low Stress Injection Molded Plastic		100% matte Sn	MSL1 [2]	595E XXXX	

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX



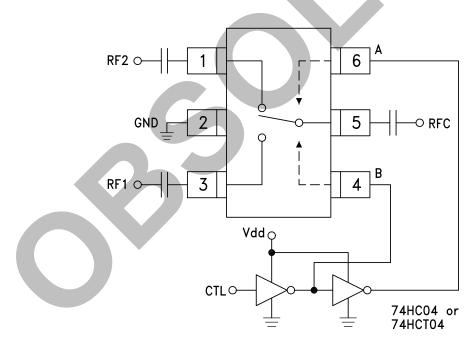


## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 3, 5	RF2, RF1, RFC	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.	
2	GND	This pin must be connected to RF/DC ground.	○ GND =
4	В	See truth table and control voltage table.	R
6	А	See truth table and control voltage table.	± c

### **Typical Application Circuit**



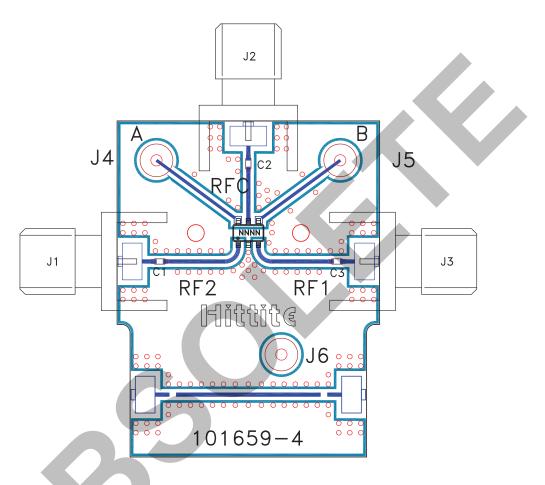
#### Notes:

- 1. Set logic gate and switch Vdd = +3V to +5V and use HCT series logic to provide a TTL driver interface.
- 2. Control inputs A/B can be driven directly with CMOS logic (HC) with Vdd of +3 to +8 Volts applied to the CMOS logic gates.
- 3. DC Blocking capacitors are required for each RF port as shown. Capacitor value determines lowest frequency of operation.
- 4. Highest RF signal power capability is achieved with V set to +10V. The switch will operate properly (but at lower RF power capability) at bias voltages down to +3V.



## GaAs MMIC 3 WATT T/R SWITCH, DC - 3 GHz

### **Evaluation Circuit Board**



### List of Materials for Evaluation PCB 101675 [1]

Item			Description	
J1 - J3			PCB Mount SMA RF Connector	
J4 - J6			DC Pin	
C1 - C3			330 pF capacitor, 0402 Pkg.	
U1	U1 HMC595 / HMC595E T/R Switch			
PCB [2]			101659 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.





Notes:



